

Product data sheet

1. General description

Ultrafast power diode in a SOT226A (I2PAK) plastic package.

2. Features and benefits

- Fast switching
- High thermal cycling performance
- Low forward voltage drop
- Low profile package facilitates compact/slim designs
- Low switching losses
- Low thermal resistance
- Soft recovery minimizes power-consuming oscillations

3. Applications

- Discontinuous Current Mode (DCM) Power Factor Correction (PFC)
- High frequency switched-mode power supplies

4. Quick reference data

Table	1.	Quick	reference	data
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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _R	reverse voltage	DC; T _{mb} ≤ 100 °C	-	-	600	V
I _{F(AV)}	average forward current	δ = 0.5; T _{mb} ≤ 135 °C; SQW; <u>Fig. 1;</u> Fig. 2	-	-	5	A
I _{FSM}	non-repetitive peak	t _p = 8.3 ms; T _{j(init)} = 25 °C; SIN	-	-	66	А
	forward current	t _p = 10 ms; T _{j(init)} = 25 °C; SIN	-	-	60	А
Static chara	acteristics					
V _F	forward voltage	I _F = 5 A; <u>Fig. 4</u>	-	1.12	1.3	V
		I _F = 5 A; T _{mb} ≤ 150 °C; <u>Fig. 4</u>	-	0.97	1.11	V
Dynamic ch	aracteristics					
t _{rr}	reverse recovery time	I _F = 1 A; V _R = 30 V; dI _F /dt = 100 A/μs; T _j = 25 °C; <u>Fig. 5</u>	-	50	60	ns

5. Pinning information

Table 2. F	Pinning inf	formation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	n.c.	not connected		K – K – A
2	К	cathode		001aaa020
3	А	anode	0	
mb	К	mounting base; cathode	1 2 3 12PAK (SOT226A)	

6. Ordering information

Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
BYV25G-600	I2PAK	plastic single-ended package (I2PAK); TO-262	SOT226A			

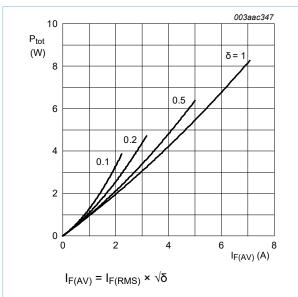


7. Limiting values

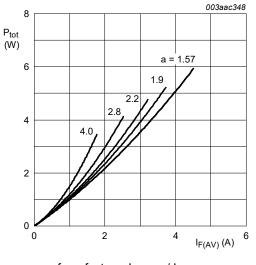
Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{RRM}	repetitive peak reverse voltage		-	600	V
V _{RWM}	crest working reverse voltage		-	600	V
V _R	reverse voltage	DC; T _{mb} ≤ 100 °C	-	600	V
I _{F(AV)}	average forward current	δ = 0.5 ; T _{mb} ≤ 135 °C; SQW; <u>Fig. 1;</u> <u>Fig. 2</u>	-	5	A
I _{FRM}	repetitive peak forward current	δ = 0.5 ;T _{mb} ≤ 135 °C; SQW	-	10	A
I _{FSM}	non-repetitive peak	t _p = 8.3 ms; T _{j(init)} = 25 °C; SIN	-	66	А
	forward current	t _p = 10 ms; T _{j(init)} = 25 °C; SIN	-	60	А
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	150	°C







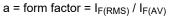


Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values



8. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	with heasink compound; Fig. 3	-	-	2.5	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air		-	60	-	K/W

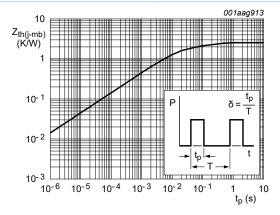
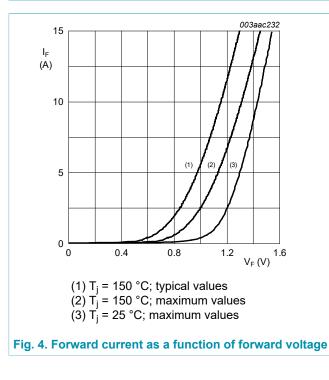


Fig. 3. Transient thermal impedance from junction to mounting base as a function of pulse width



9. Characteristics

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	cteristics					
V _F	forward voltage	I _F = 5 A; <u>Fig. 4</u>	-	1.12	1.3	V
		I _F = 5 A; T _{mb} ≤ 150 °C; <u>Fig. 4</u>	-	0.97	1.11	V
I _R	reverse current	V _R = 600 V; T _j = 100 °C	-	0.1	0.35	mA
		V _R = 600 V	-	2	50	μA
Dynamic ch	aracteristics					
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; \text{d} I_F/\text{d} t = 100 \text{ A}/\mu\text{s}; \\ T_j = 25 ^\circ\text{C}; \underline{\text{Fig. 5}}$	-	50	60	ns
I _{RM}	peak reverse recovery current	$ I_F = 10 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 50 A/\mu\text{s}; \\ T_j = 100 ^\circ\text{C}; \underline{\text{Fig. 5}} $	-	3	5.5	A
Q _r	recovered charge	$I_F = 2 \text{ A}; V_R = 30 \text{ V}; \text{ d}I_F/\text{d}t = 20 \text{ A}/\mu\text{s};$ Fig. 5	-	40	70	nC
V _{FR}	forward recovery voltage	I _F = 10 A; dI _F /dt = 10 A/μs; <u>Fig. 6</u>	-	3.2	-	V



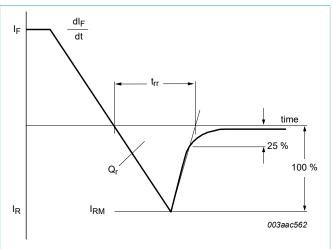
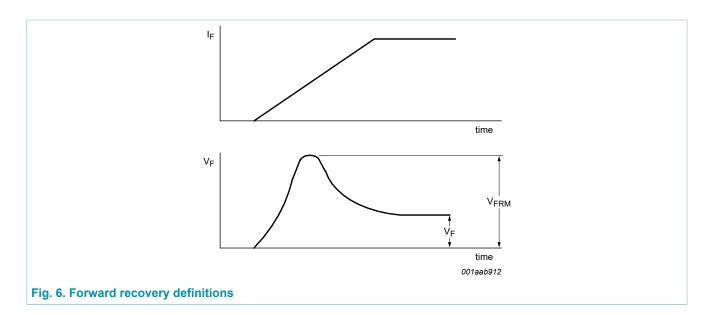


Fig. 5. Reverse recovery definitions; ramp recovery

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10. Package outline

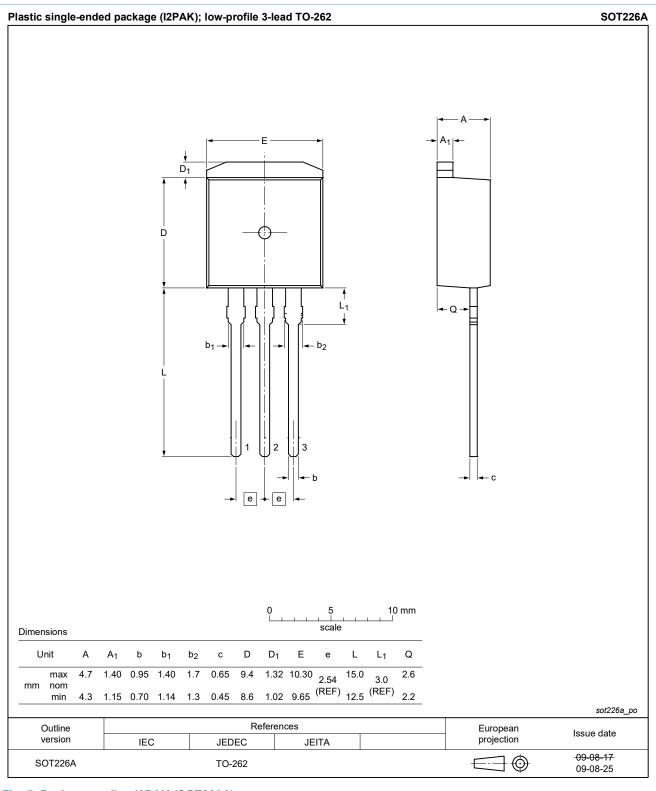


Fig. 7. Package outline I2PAK (SOT226A)

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11. Legal information

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Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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